



AFBR-S4KTIA33XXB Series SiPM TIA Module, WB-Type 3 x 3 mm² Active Area, 15/25 µm SPAD Pitch



Description

The Broadcom® AFBR-S4KTIA33XXB is a single silicon photomultiplier (SiPM) module with an integrated transimpedance amplifier (TIA) and bias source.

The SiPM module is well-suited for a wide range of fluorescence applications such as Flow Cytometry as well as those requiring single-photon counting or measurements with scintillators.

Features

- AFBR-S4K33C0115B or AFBR-S4K33C0125B SiPM
- Integrated Transimpedance Amplifier (TIA)
- Integrated Controllable Bias Source for SiPM
- Optionally with integrated Gain Stabilization
- Plug and Play Solution to replace PMTs
- Compatible with:-
- Thorlabs SM05 16 mm Optical Cage Systems
- Hamamatsu PMT mounts

Applications

- Biophotonics
 - Cytometry
 - Fluorescence Measurements
 - Point-of-Care Diagnostics
- Hazard and Threat Detection
 - Single Photon Counting
 - Scintillator Readout
 - Handheld Devices
- High Energy Physics
 - Low Light Level DetectionHigh Linearity Measurements
 - Energy Measurements

NOTE: All values in this data sheet are typical values if not marked with min., max., <, or >.

General Parameters and Ordering Information

| Туре | Active Area of SiPM Pixel [mm ²] | Microcell Size of SiPM Pixel [µm] | No. of Microcells | Gain stabilized vs. Temperature |
|-----------------------------|---|--------------------------------------|-------------------|------------------------------------|
| AFBR-S4K33TIA3315B based on | 3.0 × 3.0 | 15 | 38800 | No |
| AFBR-S4K33C0115B SiPM | | | | |
| AFBR-S4K33TIA3325B based on | 3.0 × 3.0 | 25 | 13920 | No |
| AFBR-S4K33C0125B SiPM | | | | |

Recommended Operation Parameters

| Parameter | Description |
|-----------------------|--|
| Ctrl Voltage: | 0.7V (resulting SiPM over voltage of about 5V) |
| AFBR-S4KTIA3315B | |
| AFBR-S4KTIA3325B | |
| Operating Temperature | 0°C to 60°C |

Electrical and Optical Characteristics at 21°C (typ.)

| | | | | Afterpulsing Probability [%] | Recovery Time [ns] |
|-----------------------------------|---------------|-----|----|---------------------------------|--------------------|
| AFBR-S4KTIA3315B @ Ctrl = 0.7V | 31 (@ 430 nm) | 125 | 18 | 5 | 15 |
| AFBR-S4KTIA3325B @ Ctrl = 0.7V | 45 (@ 430 nm) | 125 | 26 | <1 | 35 |

a. A Full SiPM specification can be found in the corresponding SiPM data sheet, visit https://www.broadcom.com/products/optical-sensors/silicon-photomultiplier-sipm

Interfaces and Electrical Ratings

| Parameter | Description |
|------------------------------------|---|
| Outer Dimensions | 40.0 × 50.0 x 19.8 mm³ (L x W x H) |
| Mechanical Compatibility | Thorlabs SM05 Optics and 16 mm cage system Hamamatsu PMT mounts |
| Power Supply Input | +5V DC (± 0.5V, max + 12V DC), 500 mA, MCX connector |
| | Recommended ripple noise < 10 mV |
| Typical Power Consumption | 350 mW (69 mA @ 5V power supply) |
| Bias Voltage / Gain Control (Ctrl) | 0V to +1V (min0.2V, max. +1.2V), 50 mA, MCX connector |
| Signal Output (Signal) | Output range 0V to +1V, positive polarity |
| | MCX connector matched to 50Ω impedance |
| Max. recommended Cable Length | 3m |

Electrical Characteristics of Signal Output

| Parameter | Description |
|--------------------------------------|--|
| Transimpedance Amplifier Gain | 2-stage design, total gain 150 V/A |
| Signal Output Bandwidth | 12.5 MHz |
| Signal Output Amplitude Noise | 500 μV (σ, AC coupled, 20 MHz bandwidth) |
| Bias Voltage/Gain Control (Ctrl) | 0V to +1V, 50 mA, MCX connector |
| Output Offset Tuning Range | Preset to 0V, upon request –1V to 0V |
| Output Offset Drift with Temperature | < 0.5 mV/K |

Electrical Characteristics of Internal SiPM Bias Supply

| Parameter | Description |
|-------------------------------------|---|
| Bias Voltage Range AFBR-S4KTIA3315B | 26.81V to 34.00V (SiPM Vbd at typ. 26.9V @ 21°C, no internal SiPM amplification below Vbd) |
| Bias Voltage Range AFBR-S4KTIA3325B | 24.69V to 31.55V (SiPM Vbd at typ. 24.7V @ 21°C, no internal SiPM amplification below Vbd) |
| Ripple Noise | < 2 mV min-max (1 MΩ input resistance, 22 pF capacitive load, 0.5 m RG-174-U cable) |
| Stability | < 5 mV min-max (f = 0.1 Hz) |
| Input Impedance | 400 kΩ |
| Settling Time | 0.5s (time to reach stable SiPM bias after change of Ctrl voltage) |
| Output Current Limit | 10 mA |

Typical Performance Characteristics

Figure 1: SiPM Bias Voltage vs. Ctrl Voltage

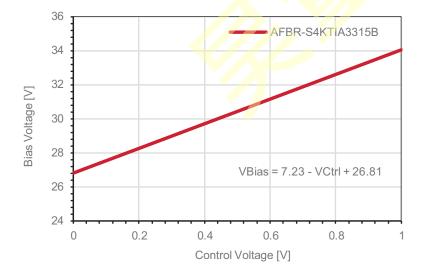


Figure 2: SiPM Bias Voltage vs. Ctrl Voltage

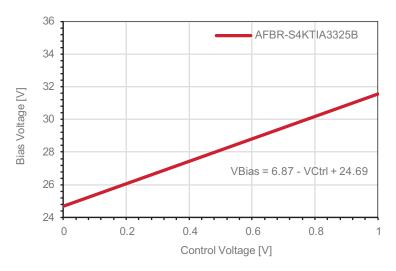
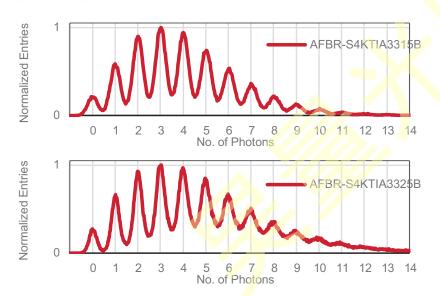
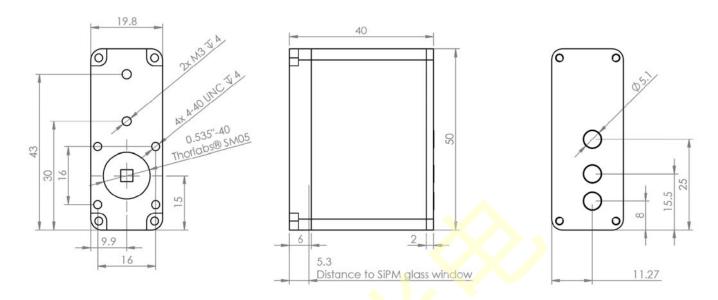


Figure 3: Single Photon Spectrum Example



Mechanical Specifications¹

Figure 4: Mechanical Specifications



^{1.} General tolerances ± 0.1 mm unless otherwise noted